

# SANYO Semiconductors DATA SHEET

# LC7932, 7932M— CMOS IC 16-Bit LED Driver

### **Overview**

The LC7932, 7932M are LSIs that contain a 16-bit bidirectional shift register and are capable of direct driving a multiple lighting LED (dot matrix or dot array). The LC7932, 7932M are especially suited for use in LED display panel, PPC photosensitive drum LED erase head applications.

### **Features**

- Silicon gate C-MOS device capable of high-speed, high-current drive.
- High-speed shiftable 16-bit bidirectional shift register/16-bit latch/output control circuit/16-bit N-channel transistor open drain output transistor on chip.
- Serial shift data is shifted on the positive transition of the clock (CLOCK) pulse.
- The data latch circuit outputs input data when the latch control (LATCH) pin is at L-level and holds output data when the latch control (LATCH) pin is at H-level.
- Maximum ratings of driver output: V<sub>0</sub> = +15V, I<sub>OL</sub> = 30mA (STATIC)/120mA(DYNAMIC).
- Operating voltage of logic unit:  $V_{DD} = 4.5 \text{V}$  to 5.5V.
- Operating clock frequency: f<sub>CLK</sub> = DC to 5MHz (max).
- Package: LC7932 : DIP30S

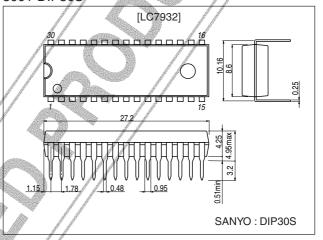
LC7932M: MFP30S

- The bidirectional shift register is so designed as to cause a shift to occur in the SI to SO direction when L/R = L-level and in the SO to SI direction when L/R = H-level.
- When a high level is applied to the LSET pin ("latch set"), the latch data is set to the high level. The latch data does not change when the LSET pin is low or open.

## Package Dimensions

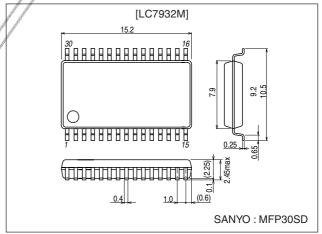
unit:mm

3061-DIP30\$



#### unit:mm

#### 3073B-MFP30SD



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# **Specifications**

## **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions		Ratings	Unit
Maximum supply voltage	V <sub>DD</sub> max			-0.3 to +7.0	V
Input voltage	VI		1	-0.3 to V <sub>DD</sub> +0.3	V
Output voltage	V <sub>O</sub> 1	SOUT (SIN) output		-0.3 to V <sub>DD</sub> +0.3	V
Output voltage	V <sub>O</sub> 2	D1 to D16 output, output Tr OFF		15	V
Output current	lo	D1 to D16 output, per output pin		30	mA
Allowable power dissipation	Pd max	LC7932 Ta = 85°C		400	mW
	Fulliax	LC7932M Ta = 85°C		270	// mW
Operating temperature	Topr			–25 to +85	°C
Storage temperature	Tstg	(Note)	// 💉	-35 to +125	°C

## Note

When mounting the MFP package version, do not dip it in solder.

# Allowable Operating Conditions at $Ta = -25^{\circ}C$ to $+85^{\circ}C$

Parameter	Symbol	Conditions	7 /	Ratings		
T didilotoi		OCHUMENS .	min	typ	max	Unit
Supply voltage	$V_{DD}$	$V_{DD}$	4.5		5.5	V
Input high-level voltage	V <sub>IH</sub>	SIN (SOUT), CLOCK, LATCH, BEO, STROBE, LSET, L/R	0.8V <sub>DD</sub>		V <sub>DD</sub>	V
Input low-level voltage	V <sub>IL</sub>	SIN (SOUT), CLOCK, LATCH, BEO, STROBE, LSET, L/R	V <sub>SS</sub> (L)		0.2V <sub>DD</sub>	V
Clock frequency	fCLK	CLOCK: Duty: 50%			5.0	MHz
Clock pulse width	t <sub>WΦ</sub>	CLOCK	75			ns
Clock rise/fall time	t <sub>r,</sub> t <sub>f</sub>	CLØCK			200	ns
Data setup time	t <sub>DS</sub>	SÍN (SOUT), CLOCK	100			ns
Data hold time	t <sub>DH</sub>	SIN (SOUT), CLOCK	50			ns
Latch pulse width	twL	LATCH	100			ns

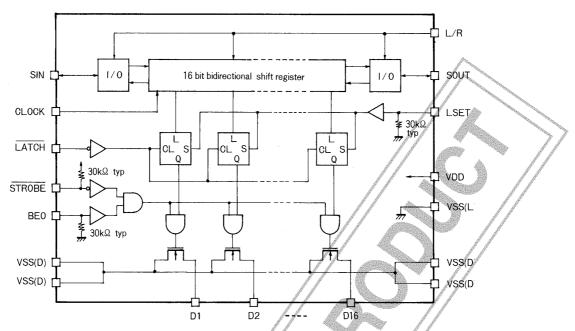
# Electrical Characteristics at Ta = 25°C

Parameter	Symbol Conditions		Ratings			Unit
raidilletei			min	typ	max	Onit
Input high-level voltage	I <sub>IH</sub> 1	SIN (SOUT), CLOCK, LATCH, L/R			10	μΑ
Input high-level voltage	l <sub>IH</sub> 2	BEO, LSET		170		μΑ
Input low-level current	ſ <sub>IL</sub> 1	SIN (SOUT), CLOCK, EATCH, L/R	-10			μΑ
Imput low-level current	I <sub>IL</sub> 2	STROBE		170		μA
Output high-level voltage	V <sub>OH</sub>	SOUT (SIN): I <sub>OH</sub> =-0.5mA, V <sub>DD</sub> =5V	V <sub>DD</sub> -0.5			V
Output low-level voltage	V <sub>OL</sub> 1	SOUT (SIN): I <sub>OL</sub> =0.5mA, V <sub>DD</sub> =5V			0.5	V
Output low-level voltage	V <sub>OL</sub> 2	D1 to D16: I <sub>OL</sub> =30mA, V <sub>DD</sub> =5V			0.5	V
Output OFF-state leakage current	loff /	D1 to D16: V <sub>O</sub> =15V			20	μΑ
nput capacitance C <sub>IN</sub> CLOCK			5.0		pF	
Operating current	lpb/	$V_{DD:}$ $f_{CLK}$ =5MHz, $V_{DD}$ =5V, All outputs with no load			5	mA

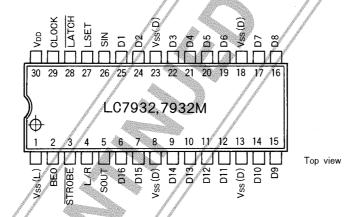
# Switching Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
rainietei	Symbol	Conditions		typ	max	Offic
Clock latch delay width	tCL	CLOCK, LATCH: V <sub>DD</sub> =5V	100			ns
Latch clock delay width	tLC	CLOCK, LATCH: V <sub>DD</sub> =5V	0			ns
	tPLH1	$V_{DD}$ =5V LATCH, D1 to D16: Dn; (RL=1.0kΩ, CL=15pF),			400	ns
Output high-level propagation delay time	t <sub>PLH</sub> 2	BEO, $\overline{\text{STROBE}}$ , D1 to D16: Dn; (RL=1.0k $\Omega$ , CL=15pF), V <sub>DD</sub> =5V			300	ns
	t <sub>PLH</sub> 3	CLOCK, SOUT (SIN) : SOUT; CL=15pF, V <sub>DD</sub> =5V			200	ns
	t <sub>PHL</sub> 1	LATCH, LSET, D1 to D16: Dn; (RL=1.0k $\Omega$ , CL=15pF), V <sub>DD</sub> =5V			200	ns
Output low-level propagation delay time	t <sub>PHL</sub> 2	BEO, $\overline{\text{STROBE}}$ , D1 to D16: Dn; (RL=1.0k $\Omega$ , CL=15pF), VDD=5V			100	ns
	t <sub>PHL</sub> 3	CLOCK, SOUT (SIN) : SOUT; CL=15pF, V <sub>DD</sub> =5V			200	ns

## **Equivalent Circuit**



## **Pin Assignment**

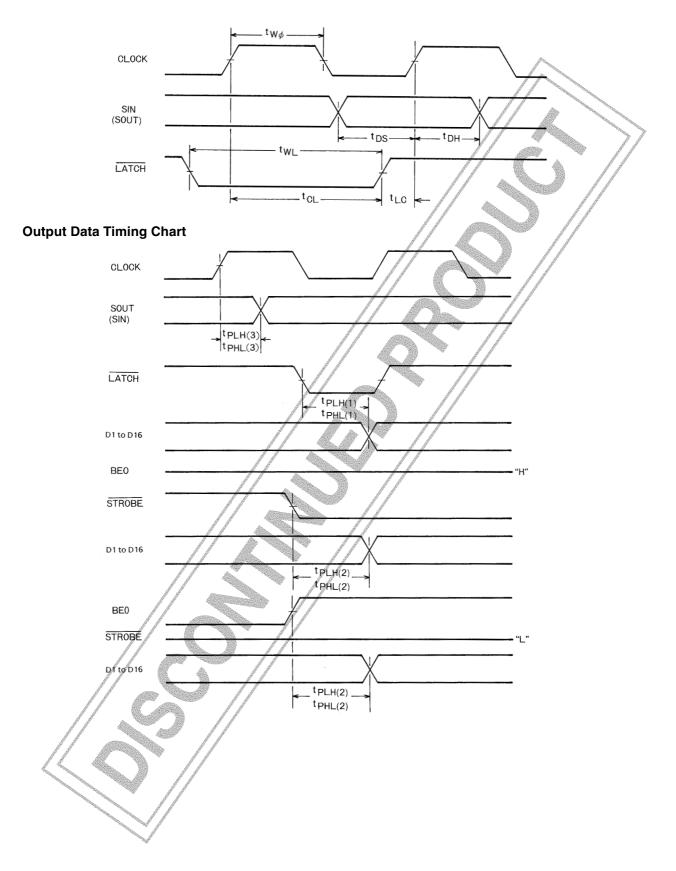


The package comes in two types-DIP30S and MFP30S.

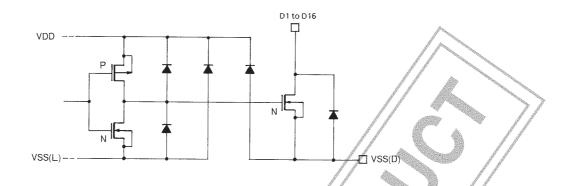
# **LED Driver ON/OFF Truth Table**

	2	
Latch Data (Q) BEO	STROBE	LED Driver
0 0	0	OFF
1 0	0	OFF
0 1	0	OFF
1 1	0	ON Driver ON
0 0	1	OFF
1 0	1	OFF
0 1	1	OFF
1 1	1	OFF

## **Input Data Timing Chart**



#### **Equivalent Circuit for Output Driver Section**



#### Note

L/R = H-level: ( )

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